Electronic/Optoelectronic Memory Device Enabled by 7 Heterostructure for in‧ensor Reservoir Computing a

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Citation Report

#	Article	IF	CITATIONS
1	Recent Advances in Layered Twoâ€Ðimensional Ferroelectrics from Material to Device. Advanced Functional Materials, 2023, 33, .	14.9	1
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15	Asymmetrically Contacted Tellurium Shortâ€Wave Infrared Photodetector with Low Dark Current and High Sensitivity at Room Temperature. Advanced Optical Materials, 2023, 11, .	7.3	3
16	Editorial: Cutting-edge systems and materials for brain-inspired computing, adaptive bio-interfacing and smart sensing: implications for neuromorphic computing and biointegrated frameworks. Frontiers in Neuroscience, 0, 17, .	2.8	0
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